

# MC14093B

## Quad 2-Input "NAND" Schmitt Trigger

The MC14093B Schmitt trigger is constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. These devices find primary use where low power dissipation and/or high noise immunity is desired. The MC14093B may be used in place of the MC14011B quad 2-input NAND gate for enhanced noise immunity or to "square up" slowly changing waveforms.

- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range
- Triple Diode Protection on All Inputs
- Pin-for-Pin Compatible with CD4093
- Can be Used to Replace MC14011B
- Independent Schmitt-Trigger at each Input

### MAXIMUM RATINGS\* (Voltages Referenced to V<sub>SS</sub>)

Symbol	Parameter	Value	Unit
V <sub>DD</sub>	DC Supply Voltage	- 0.5 to + 18.0	V
V <sub>in</sub> , V <sub>out</sub>	Input or Output Voltage (DC or Transient)	- 0.5 to V <sub>DD</sub> + 0.5	V
I <sub>in</sub> , I <sub>out</sub>	Input or Output Current (DC or Transient), per Pin	± 10	mA
P <sub>D</sub>	Power Dissipation, per Package†	500	mW
T <sub>stg</sub>	Storage Temperature	- 65 to + 150	°C
T <sub>L</sub>	Lead Temperature (8-Second Soldering)	260	°C

\* Maximum Ratings are those values beyond which damage to the device may occur.

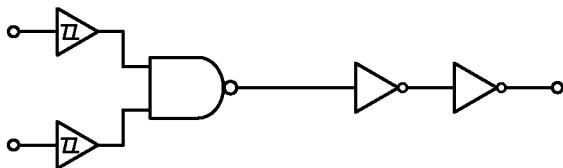
† Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

Ceramic "L" Packages: - 12 mW/°C From 100°C To 125°C

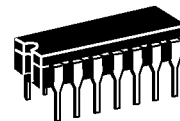
### EQUIVALENT CIRCUIT SCHEMATIC

(1/4 OF CIRCUIT SHOWN)

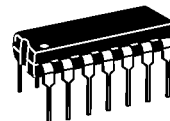


This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V<sub>in</sub> and V<sub>out</sub> should be constrained to the range V<sub>SS</sub> ≤ (V<sub>in</sub> or V<sub>out</sub>) ≤ V<sub>DD</sub>.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V<sub>SS</sub> or V<sub>DD</sub>). Unused outputs must be left open.



**L SUFFIX**  
CERAMIC  
CASE 632



**P SUFFIX**  
PLASTIC  
CASE 646



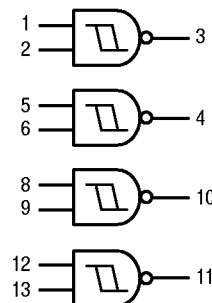
**D SUFFIX**  
SOIC  
CASE 751A

### ORDERING INFORMATION

MC14XXXBCP Plastic  
MC14XXXBCL Ceramic  
MC14XXXBD SOIC

T<sub>A</sub> = - 55° to 125°C for all packages.

### LOGIC DIAGRAM



V<sub>DD</sub> = PIN 14  
V<sub>SS</sub> = PIN 7

**ELECTRICAL CHARACTERISTICS** (Voltages Referenced to V<sub>SS</sub>)

Characteristic	Symbol	V <sub>DD</sub> Vdc	-55°C		25°C			125°C		Unit	
			Min	Max	Min	Typ #	Max	Min	Max		
Output Voltage V <sub>in</sub> = V <sub>DD</sub> or 0	"0" Level V <sub>OL</sub>	5.0	—	0.05	—	0	0.05	—	0.05	Vdc	
		10	—	0.05	—	0	0.05	—	0.05		
		15	—	0.05	—	0	0.05	—	0.05		
	"1" Level V <sub>in</sub> = 0 or V <sub>DD</sub>	V <sub>OH</sub>	5.0	4.95	—	4.95	5.0	—	4.95	—	Vdc
			10	9.95	—	9.95	10	—	9.95	—	
			15	14.95	—	14.95	15	—	14.95	—	
Output Drive Current (V <sub>OH</sub> = 2.5 Vdc) (V <sub>OH</sub> = 4.6 Vdc) (V <sub>OH</sub> = 9.5 Vdc) (V <sub>OH</sub> = 13.5 Vdc)	Source I <sub>OH</sub>	5.0	-3.0	—	-2.4	-4.2	—	-1.7	—	mA <sub>dc</sub>	
		5.0	-0.64	—	-0.51	-0.88	—	-0.36	—		
		10	-1.6	—	-1.3	-2.25	—	-0.9	—		
		15	-4.2	—	-3.4	-8.8	—	-2.4	—		
	Sink I <sub>OL</sub>	5.0	0.64	—	0.51	0.88	—	0.36	—	mA <sub>dc</sub>	
		10	1.6	—	1.3	2.25	—	0.9	—		
15		4.2	—	3.4	8.8	—	2.4	—			
Input Current	I <sub>in</sub>	15	—	±0.1	—	±0.00001	±0.1	—	±1.0	μA <sub>dc</sub>	
Input Capacitance (V <sub>in</sub> = 0)	C <sub>in</sub>	—	—	—	—	5.0	7.5	—	—	pF	
Quiescent Current (Per Package)	I <sub>DD</sub>	5.0	—	0.25	—	0.0005	0.25	—	7.5	μA <sub>dc</sub>	
		10	—	0.5	—	0.0010	0.5	—	15		
		15	—	1.0	—	0.0015	1.0	—	30		
Total Supply Current**† (Dynamic plus Quiescent, Per Package) (C <sub>L</sub> = 50 pF on all outputs, all buffers switching)	I <sub>T</sub>	5.0	I <sub>T</sub> = (1.2 μA/kHz) f + I <sub>DD</sub>							μA <sub>dc</sub>	
		10	I <sub>T</sub> = (2.4 μA/kHz) f + I <sub>DD</sub>								
		15	I <sub>T</sub> = (3.6 μA/kHz) f + I <sub>DD</sub>								
Hysteresis Voltage	V <sub>H†</sub>	5.0	0.3	2.0	0.3	1.1	2.0	0.3	2.0	Vdc	
		10	1.2	3.4	1.2	1.7	3.4	1.2	3.4		
		15	1.6	5.0	1.6	2.1	5.0	1.6	5.0		
Threshold Voltage Positive-Going	V <sub>T+</sub>	5.0	2.2	3.6	2.2	2.9	3.6	2.2	3.6	Vdc	
		10	4.6	7.1	4.6	5.9	7.1	4.6	7.1		
		15	6.8	10.8	6.8	8.8	10.8	6.8	10.8		
	Negative-Going	V <sub>T-</sub>	5.0	0.9	2.8	0.9	1.9	2.8	0.9	2.8	Vdc
			10	2.5	5.2	2.5	3.9	5.2	2.5	5.2	
			15	4.0	7.4	4.0	5.8	7.4	4.0	7.4	

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

\*\*The formulas given are for the typical characteristics only at 25°C.

†To calculate total supply current at loads other than 50 pF:

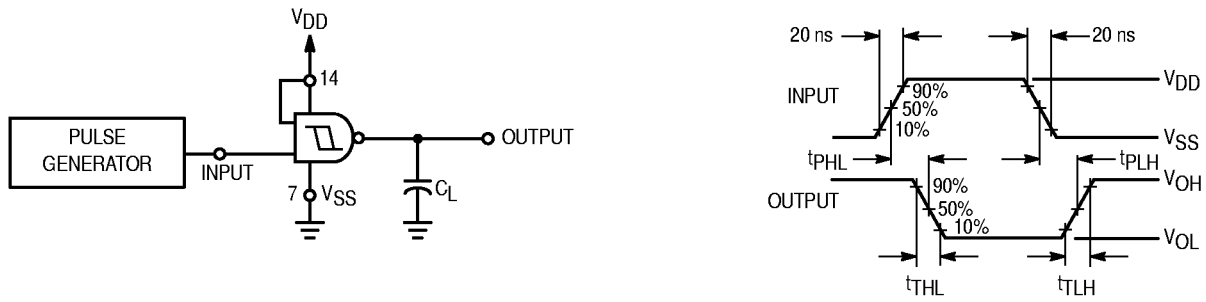
$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) Vfk$$

where: I<sub>T</sub> is in μA (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> - V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.004.

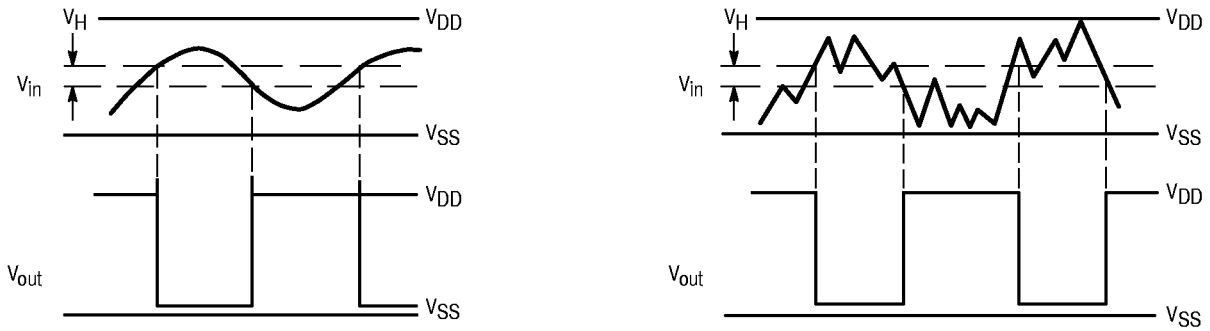
**SWITCHING CHARACTERISTICS** ( $C_L = 50 \text{ pF}$ ,  $T_A = 25^\circ\text{C}$ )

Characteristic	Symbol	$V_{DD}$ Vdc	Min	Typ #	Max	Unit
Output Rise Time	$t_{TLH}$	5.0	—	100	200	ns
		10	—	50	100	
		15	—	40	80	
Output Fall Time	$t_{THL}$	5.0	—	100	200	ns
		10	—	50	100	
		15	—	40	80	
Propagation Delay Time	$t_{PLH}$ , $t_{PHL}$	5.0	—	125	250	ns
		10	—	50	100	
		15	—	40	80	

#Data labeled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



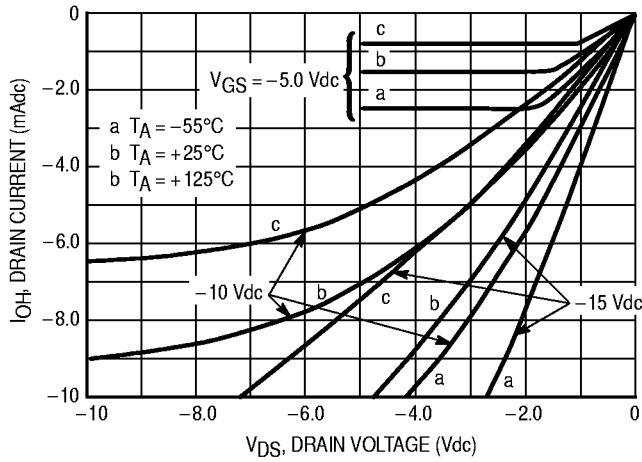
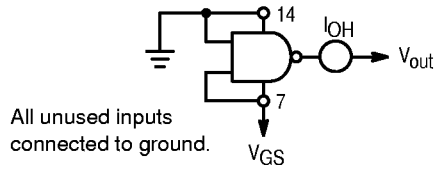
**Figure 1. Switching Time Test Circuit and Waveforms**



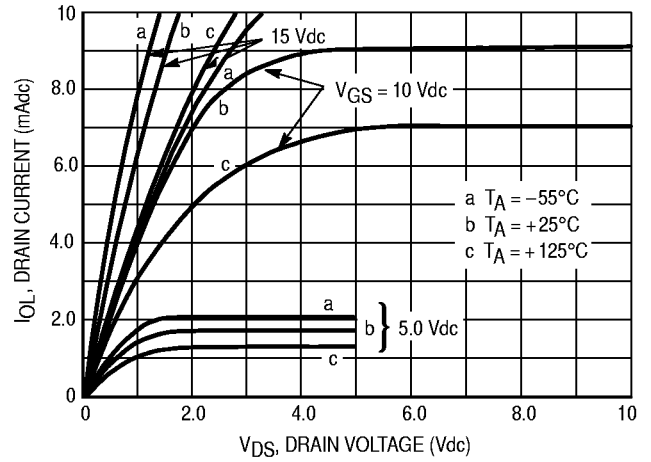
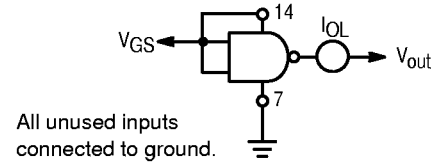
**(a) Schmitt Triggers will square up inputs with slow rise and fall times.**

**(b) A Schmitt trigger offers maximum noise immunity in gate applications.**

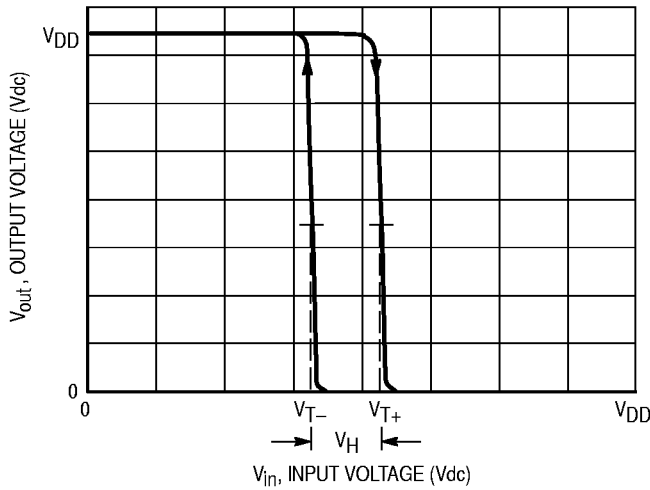
**Figure 2. Typical Schmitt Trigger Applications**



**Figure 3. Typical Output Source Characteristics Test Circuit**



**Figure 4. Typical Output Sink Characteristics Test Circuit**



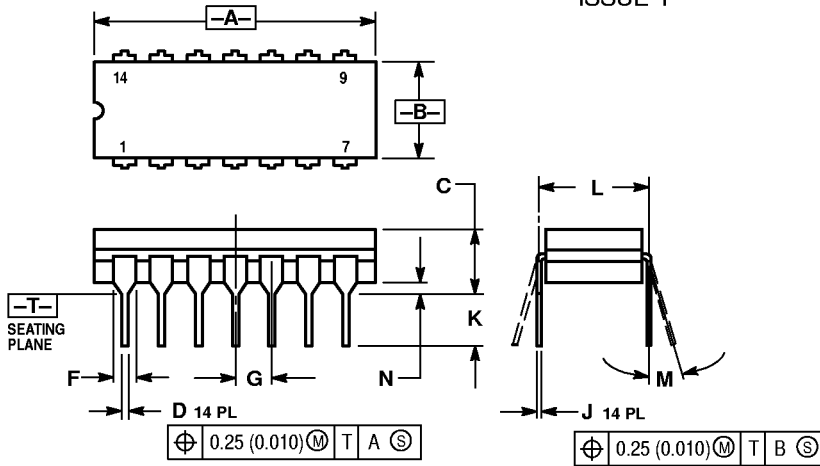
**Figure 5. Typical Transfer Characteristics**

**PIN ASSIGNMENT**

IN 1A	1	14	V <sub>DD</sub>
IN 2A	2	13	IN 2D
OUT A	3	12	IN 1D
OUT B	4	11	OUT D
IN 1B	5	10	OUT C
IN 2B	6	9	IN 2C
V <sub>SS</sub>	7	8	IN 1C

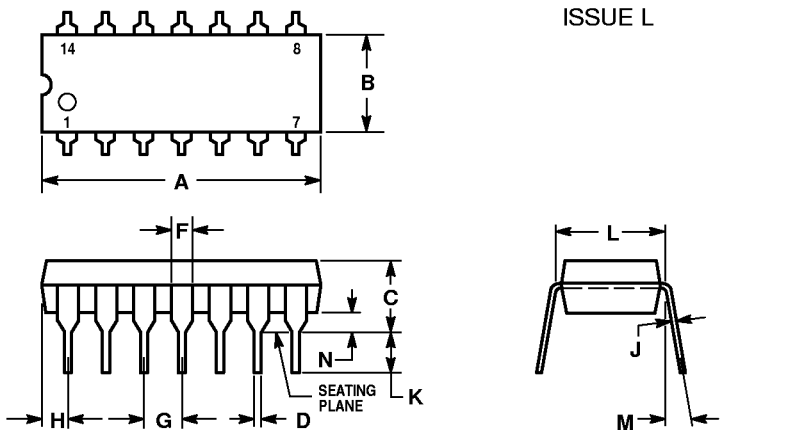
## OUTLINE DIMENSIONS

### L SUFFIX CERAMIC DIP PACKAGE CASE 632-08 ISSUE Y



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
  4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

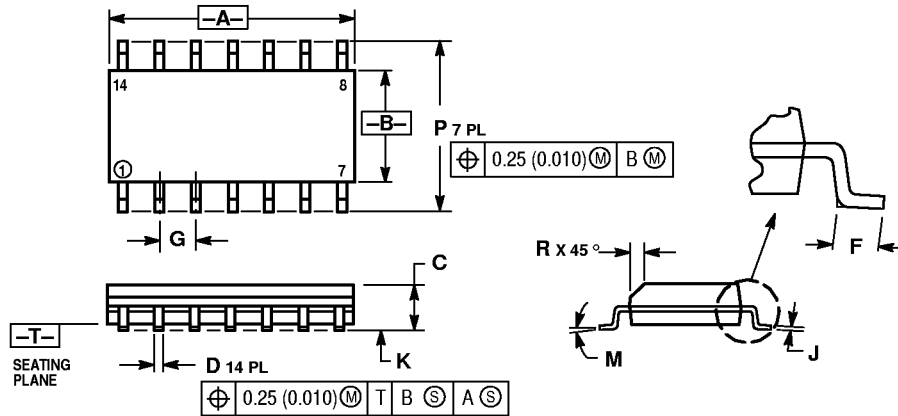
### P SUFFIX PLASTIC DIP PACKAGE CASE 646-06 ISSUE L



- NOTES:
1. LEADS WITHIN 0.13 (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
  2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
  3. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
  4. ROUNDED CORNERS OPTIONAL.

## OUTLINE DIMENSIONS


### D SUFFIX PLASTIC SOIC PACKAGE CASE 751A-03 ISSUE F



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

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MC14093B/D

